

N-channel TrenchMOS standard level FET 2 August 2013

Product data sheet

1. General description

Standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

2. Features and benefits

Low conduction losses due to low on-state resistance

3. Applications

- DC-to-DC convertors switching
- General purpose switching

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 150 °C		-	-	150	V
I _D	drain current	T _{sp} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u> ; <u>Fig. 3</u>		-	-	5	А
P _{tot}	total power dissipation	T _{sp} = 25 °C; <u>Fig. 2</u>		-	-	6.25	W
Static characte	eristics	·	1		- 1		
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; <u>Fig. 9;</u> <u>Fig. 10</u>		-	56	75	mΩ
Dynamic characteristics							
Q _{GD}	gate-drain charge	V _{GS} = 10 V; I _D = 5 A; V _{DS} = 75 V; T _j = 25 °C; <u>Fig. 11</u>		-	12	-	nC



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	8 <u>A A A A</u> 5	D
2	S	source		
3	S	source		G
4	G	gate		mbb076 S
5	D	drain	SO8 (SOT96-1)	
6	D	drain		
7	D	drain		
8	D	drain		

6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
PHK5NQ15T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHK5NQ15T	K5NQ15T

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	$T_j \ge 25 \ ^{\circ}C; \ T_j \le 150 \ ^{\circ}C$	-	150	V
V _{DGR}	drain-gate voltage	$T_j \ge 25 \text{ °C}; T_j \le 150 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$	-	150	V
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	T _{sp} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>	-	3.23	А
		T _{sp} = 25 °C; V _{GS} = 10 V; <u>Fig. 1; Fig. 3</u>	-	5	А
I _{DM}	peak drain current	T_{sp} = 25 °C; pulsed; $t_p \le 10 \ \mu s; \frac{Fig. 3}{2}$	-	20	А
P _{tot}	total power dissipation	T _{sp} = 25 °C; <u>Fig. 2</u>	-	6.25	W

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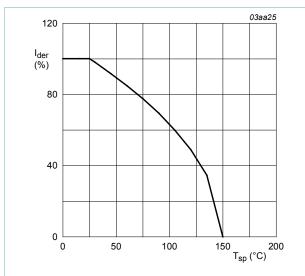
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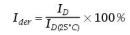
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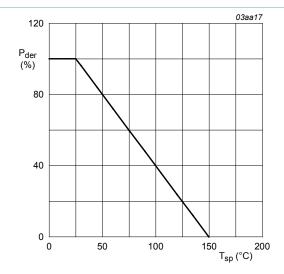
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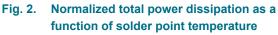
Symbol	Parameter	Conditions	Min	Max	Unit	
T _{stg}	storage temperature		-55	150	°C	
Tj	junction temperature		-55	150	°C	
Source-drain diode						
I _S	source current	T _{sp} = 25 °C	-	5	А	
I _{SM}	peak source current	T_{sp} = 25 °C; pulsed; $t_p \le 10 \ \mu s$	-	20	А	



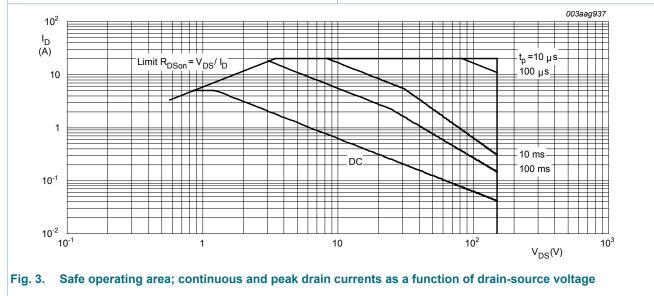








$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



 $T_{mb} = 25^{\circ}C; \ I_{DM}$ is a single pulse

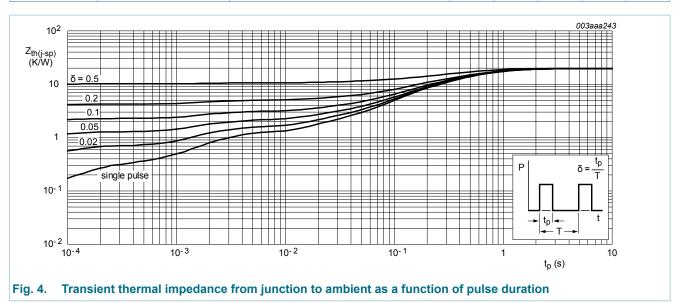
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9. Thermal characteristics

Table 6. The	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	<u>Fig. 4</u>	-	-	20	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	minimum footprint ; mounted on printed-circuit board	-	70	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics	· · ·	- I			
V _{(BR)DSS} drain-source breakdown voltage	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	134	-	-	V
	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	150	-	-	V	
V _{GS(th)} gate-source the voltage	$ \begin{array}{ll} \mbox{gate-source threshold} & I_D = 1 \mbox{ mA}; V_{DS} = V_{GS}; T_j = -55 ^\circ C; \\ \mbox{voltage} & \hline \mbox{Fig. 8} \end{array} $,	-	-	4.5	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 150 °C; Fig. 8	1.2	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; <u>Fig. 8</u>	2	3	4	V
I _{DSS}	drain leakage current	V_{DS} = 120 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
		V _{DS} = 120 V; V _{GS} = 0 V; T _j = 150 °C	-	-	100	μA
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA

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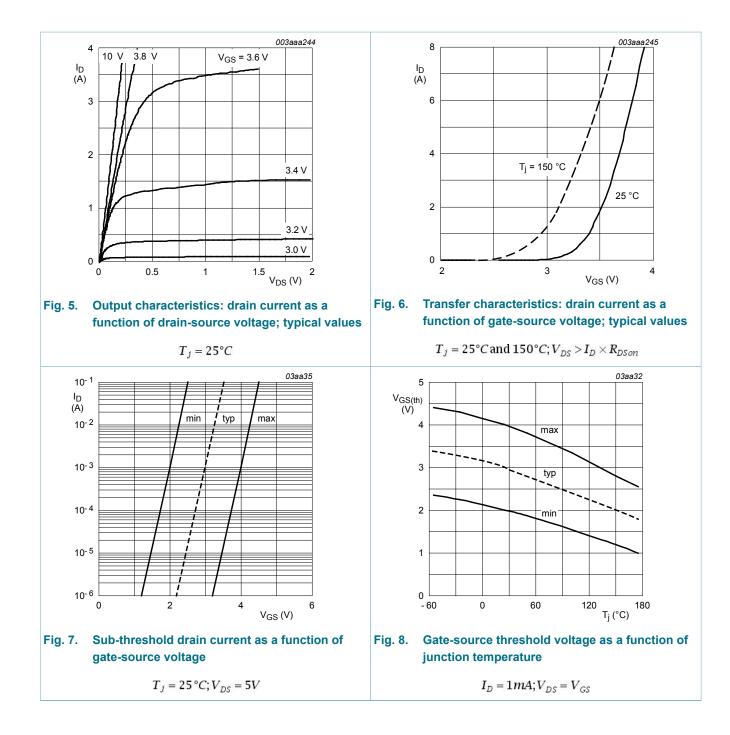
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 150 °C; Fig. 9; Fig. 10	-	129	173	mΩ
		V _{GS} = 5 V; I _D = 3 A; T _j = 25 °C	-	60	80	mΩ
		V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; <u>Fig. 9;</u> <u>Fig. 10</u>	-	56	75	mΩ
R _G	gate resistance	f = 1 MHz	-	1.9	3.8	Ω
Dynamic cł	haracteristics		I			
Q _{G(tot)}	total gate charge	I_D = 5 A; V_{DS} = 75 V; V_{GS} = 10 V;	-	29	41	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 11</u>	-	3	-	nC
Q _{GD}	gate-drain charge		-	12	-	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 12</u>	-	1150	1553	pF
C _{oss}	output capacitance		-	187	252	pF
C _{rss}	reverse transfer capacitance		-	61	85	pF
t _{d(on)}	turn-on delay time	V_{DS} = 75 V; R _L = 15 Ω; V _{GS} = 10 V;	-	12	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C; I_D = 5 A$	-	12	-	ns
t _{d(off)}	turn-off delay time		-	35	-	ns
t _f	fall time		-	18	-	ns
Source-dra	in diode	· · ·	1			
V _{SD}	source-drain voltage	I _S = 5 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 13</u>	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 5 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	87	113	ns
Q _r	recovered charge	V _{DS} = 90 V; T _j = 25 °C	-	162	-	nC

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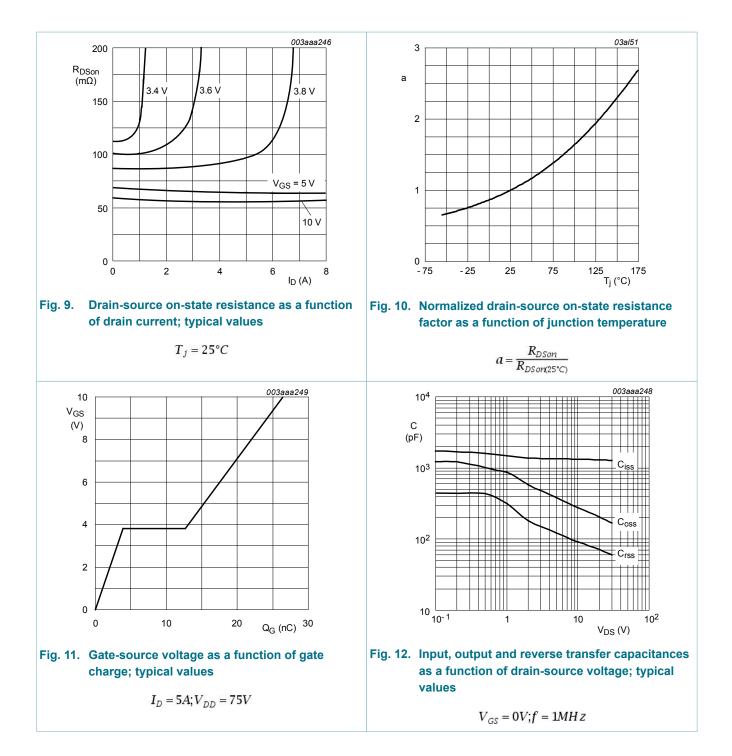
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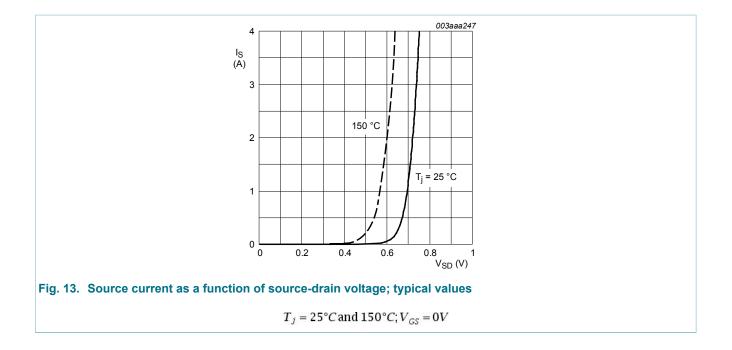


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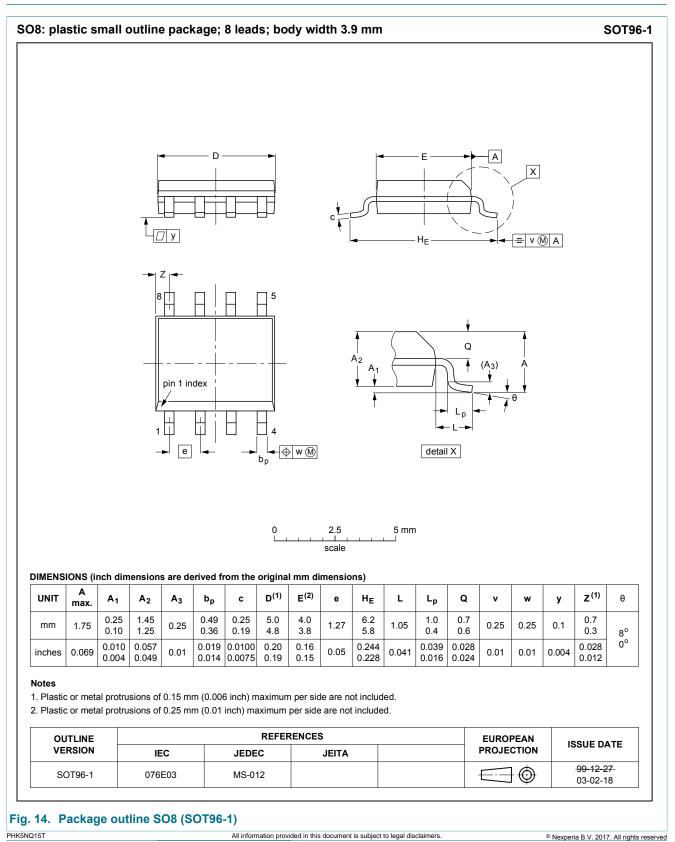
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11. Package outline



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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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